

GP1M003A050FG

GP1M003A050FG Information

	w.helseney.com	GP1M003A050FG Global Power Technologies Group Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 500V 2.5A TO220F TO-220-3 Full Pack For the pricing/inventory/lead time, please contact	
For	r Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GP1M003A050FG Specifications

Manufacturer Part Number	GP1M003A050FG
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	2.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	395pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	17.3W (Tc)
Rds On (Max) @ Id, Vgs	2.8 Ohm @ 1.25A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220F
Package / Case	TO-220-3 Full Pack
	Report errors?

GP1M003A050FG Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GP1M003A050FG Payment Methods





If you have any question about GP1M003A050FG, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com